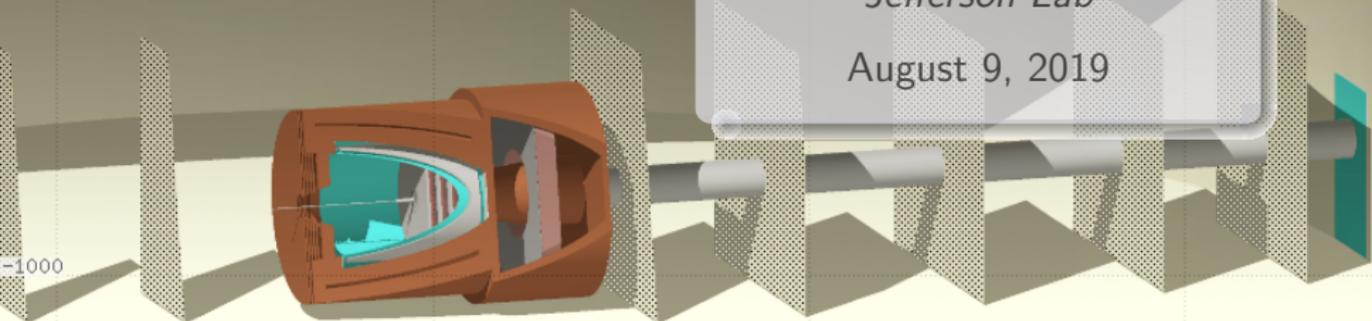


# SoLID

## Radiation and Activation with SoLID

Lorenzo Zana  
*Jefferson Lab*  
August 9, 2019



- 1 Tools Used
- 2 Source
- 3 Radiation Inside the Magnet
  - Gems PVDIS
  - Gems SIDIS
  - Gems ( $J/\psi$ )
  - Radiation on Coils
- 4 Power and Activation
  - PVDIS
  - SIDIS
- 5 Radiation in Hall at run-time
  - Goal
  - PVDIS
  - SIDIS
  - ( $J/\psi$ )
- 6 Conclusions

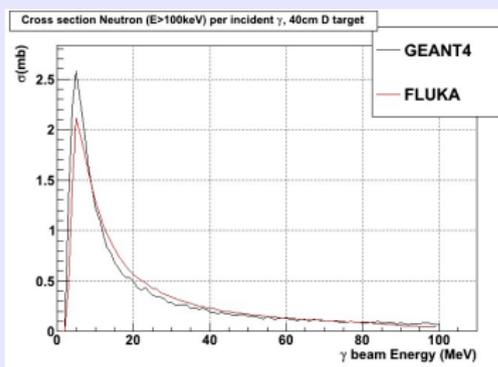
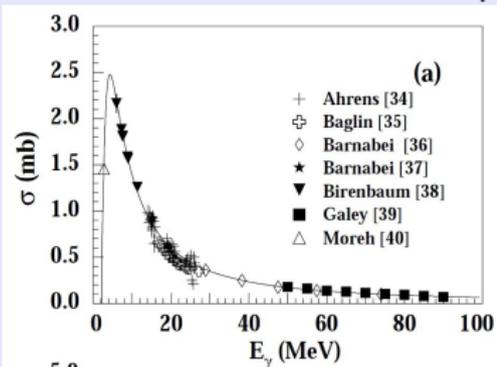






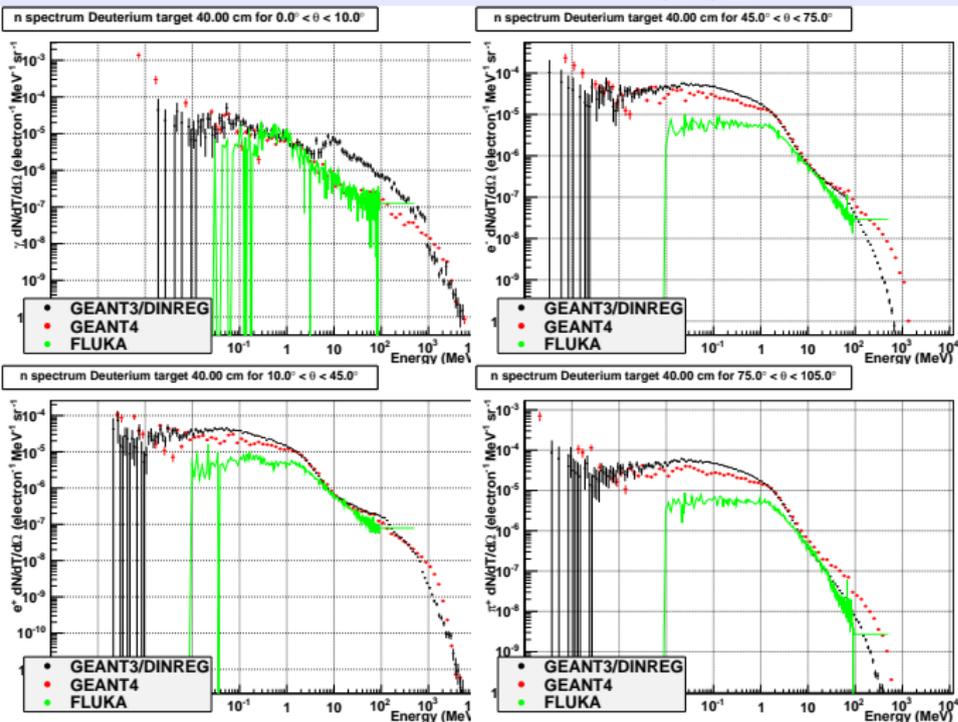
# Neutron Photo-production on Deuterium

Comparison with real cross section for FLUKA and GEANT4 for Neutron Photo-production on Deuterium



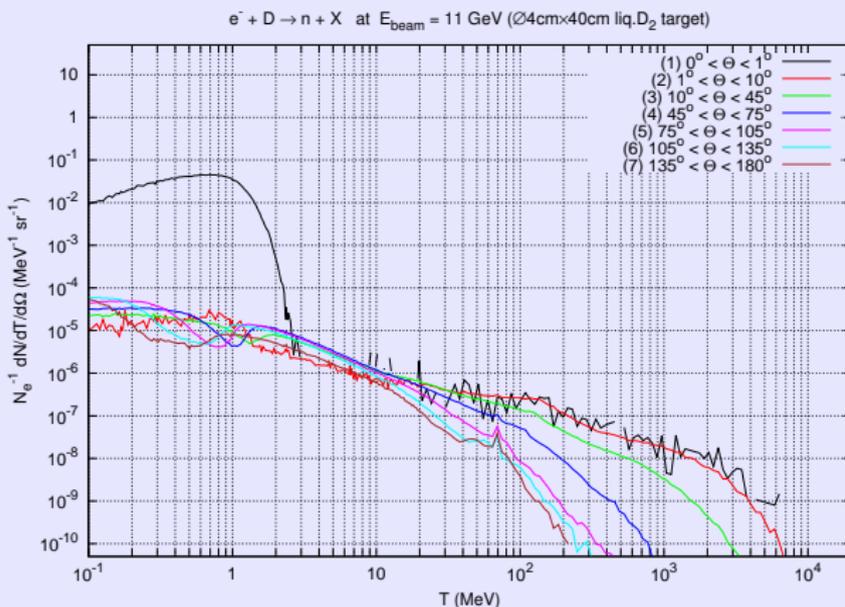
# Neutron Full Production from electron beam

## NEUTRON 40cm Deuterium $\frac{d^2N}{dT d\Omega}$



# Neutron Full Production from electron beam

NEUTRON 40cm Deuterium  $\frac{d^2N}{dT d\Omega}$  Fluka Dev version



# Neutron Full Production from electron beam

## NEUTRON 40cm Deuterium $\frac{d^2N}{dT d\Omega}$

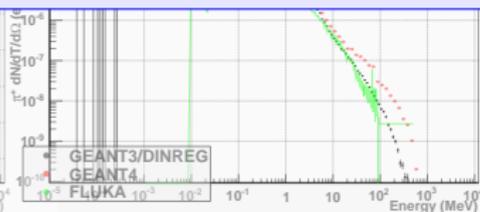
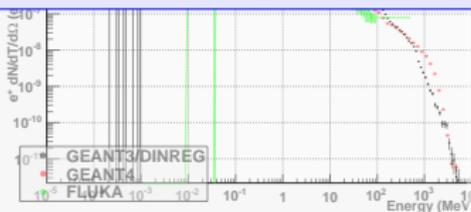
n spectrum Deuterium target 40.00 cm for  $0.0^\circ < \theta < 10.0^\circ$



n spectrum Deuterium target 40.00 cm for  $45.0^\circ < \theta < 75.0^\circ$



- Good agreement between GEANT3(DINREG) and GEANT4
- FLUKA by default lacks of direct electro-nuclear dissociation and fragmentation models (dominant in Neutron production from Liquid Deuterium). Source term implemented (not good agreement for  $\theta < 10^\circ$ ). The development version has good agreement)



# Radiation inside the Magnet

## Shielding inside the Magnet: PVDIS configuration

- Shielding inside the Magnet will be based on Borated Polyethylene
- This Shielding is expected to give the best results in mitigating the expected background radiation spectrum.
- Shielding is placed filling the space between the baffles, covering the coils on the section of the magnet outside the baffle region and in the downstream region in the available space.

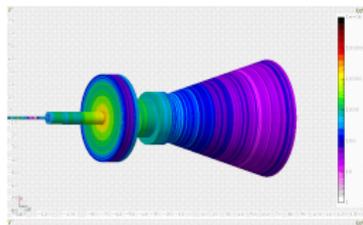
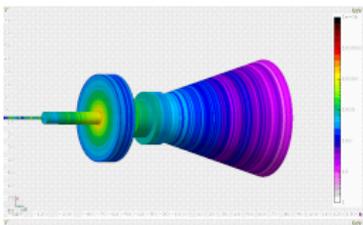
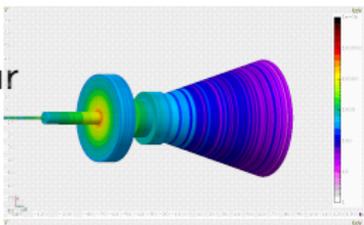
# Baffle: Different Material Activation

LEAD

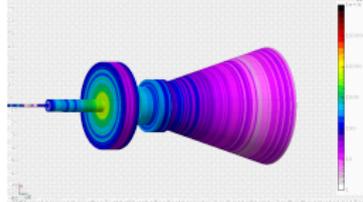
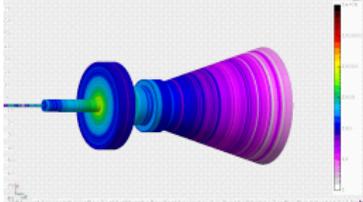
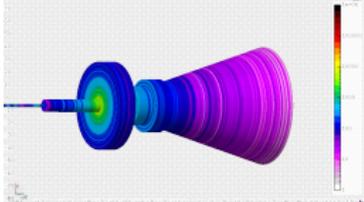
COPPER

TUNGSTEN

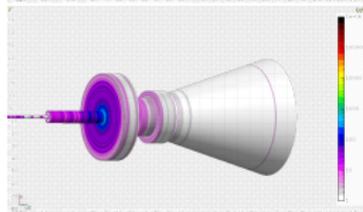
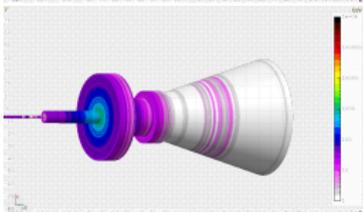
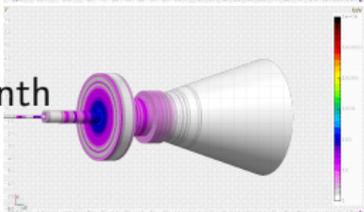
1hour



1day



1month



# Baffle: Different Material Activation

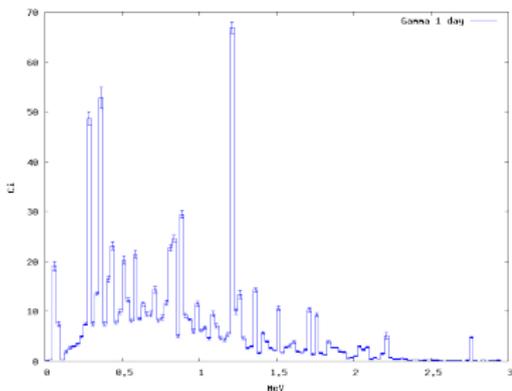
## Baffle's material Activation

- Different material were tested for the first 3 layers of baffle/shielding
- At this presentation just shown the first baffle, but material dependence is comparable also for the other baffles analyzed
- Copper shows a longer decaying time for the activated isotopes (after 1month radiation is  $\sim 1$  order of magnitude respect to Lead and Tungsten)

# Change of SoLID config: baffle activation for PVDIS

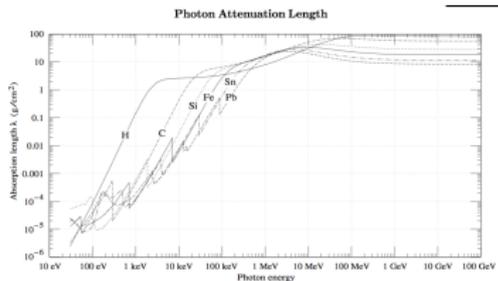
Goal for activation  $\Rightarrow < 10 \text{ mrem/h}$

Copper 1st baffle:  
 Gamma Spectrum after 1day



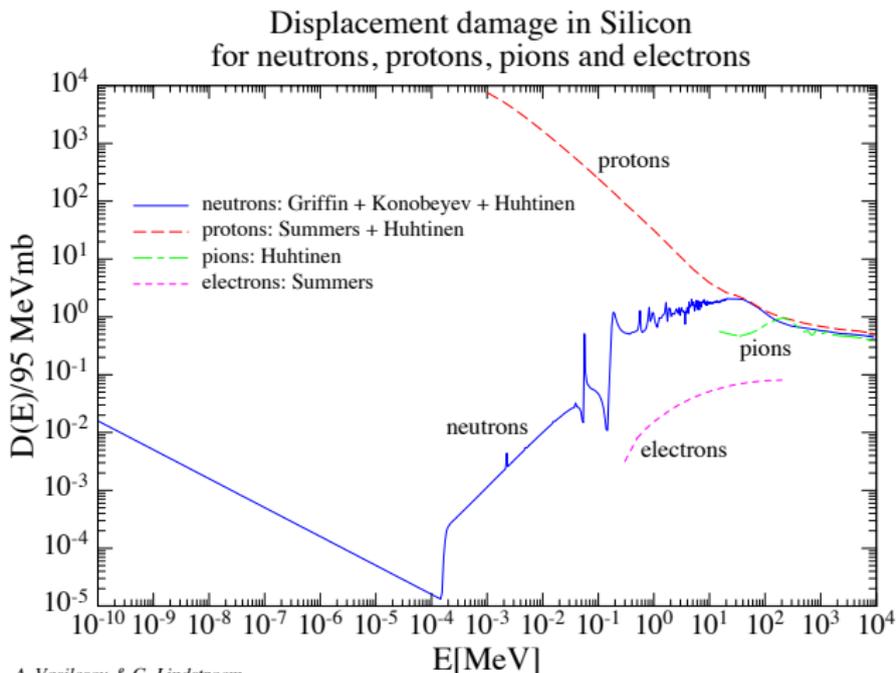
~ 8cm of Lead for goal

- factor of ~ 20 reduction
- (Real baffle has 50% of this activation)



# Displacement damage in Si, NIEL

(Non Ionizing E-Loss) for  $e^-$ ,  $p$ ,  $\pi$ ,  $n$



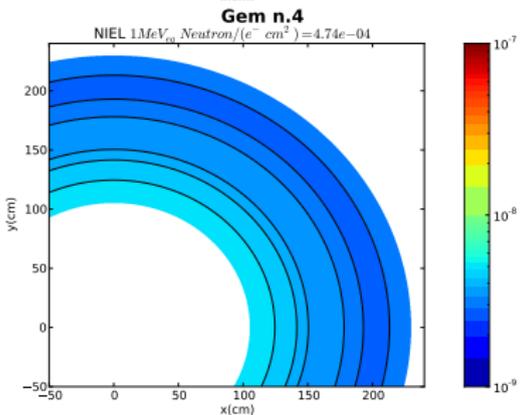
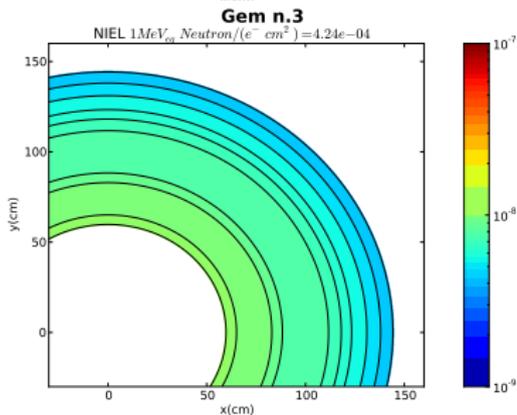
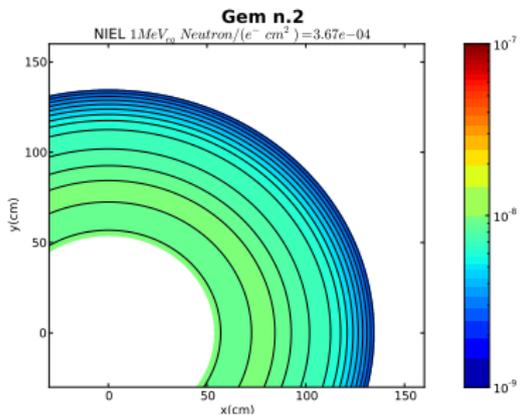
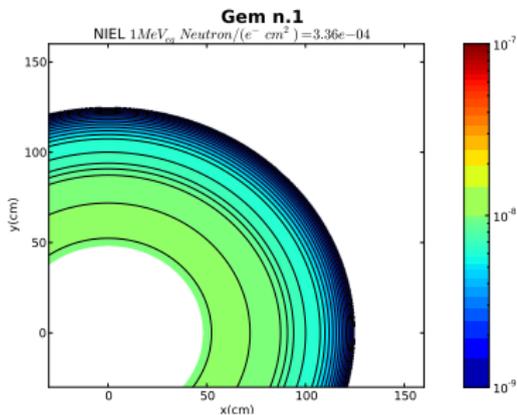
A. Vasilescu & G. Lindstroem

# Displacement damage in Si, NIEL

## What is a tolerable level for APV25 (GEM) ?

- CMS Silicon STRIP Tracker (the APV25 chip was designed for this detector) total fluence expected to peak around  $2.4 \times 10^{14} \frac{1\text{MeV}_{\text{eq}}N}{\text{cm}^2}$
- Our flux is ( 2000h at  $100\mu\text{A}$  )  
 $2.4 \times 10^{14} \frac{1\text{MeV}_{\text{eq}}N}{\text{cm}^2} \Rightarrow 5.3 \times 10^{-8} \frac{1\text{MeV}_{\text{eq}}N}{e^{-}\text{cm}^2}$
- The APV25 chips will be placed in the outer layer of the GEM

# PVDIS 1MeV<sub>eq</sub> $\frac{N}{e^{-cm^2}}$ WITH SHIELDING (ABS/SHLD = POLY)



# Radiation on SIDIS

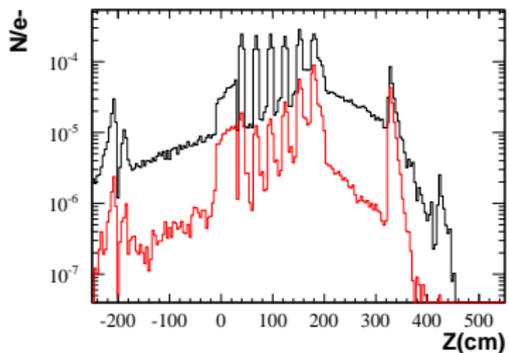
Neutron radiation dominates the PVDIS configuration.  
What is the comparison with SIDIS?

# Radiation on SIDIS

Neutron radiation dominates the PVDIS configuration.  
What is the comparison with SIDIS?

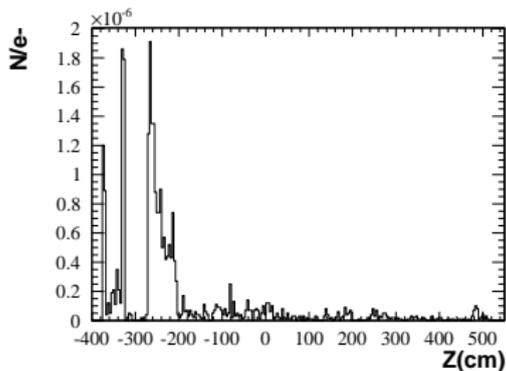
PVDIS

Vertex Z neutron



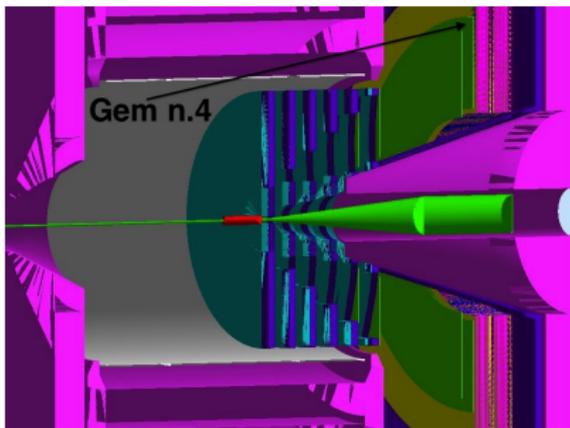
SIDIS

Vertex Z neutron

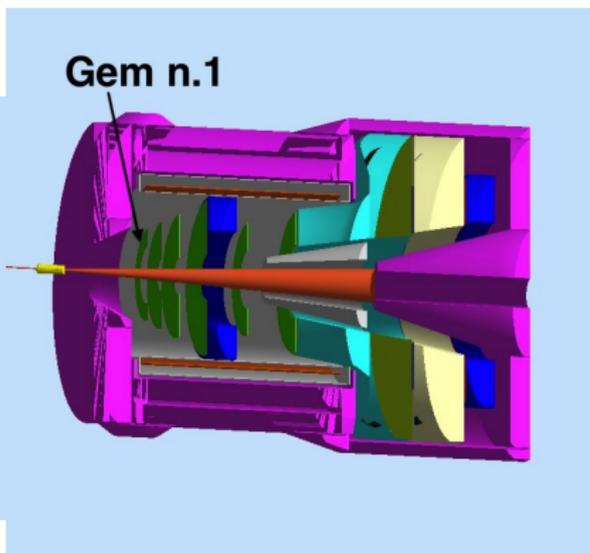


# Radiation on SIDIS

PVDIS



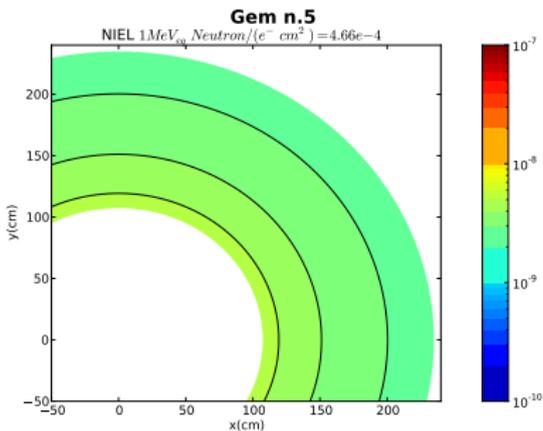
SIDIS



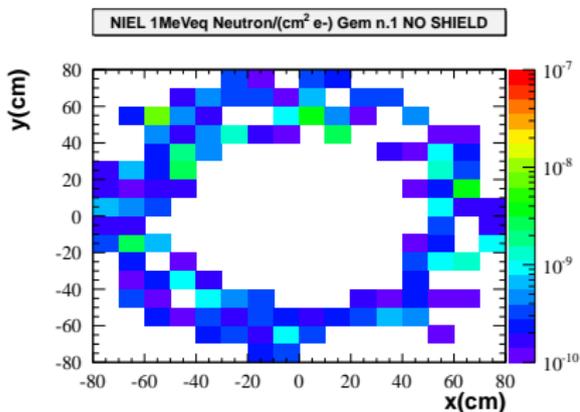
# Radiation on SIDIS

What is the comparison for 1MeV eq radiation in the gems?

PVDIS Gem n.5



SIDIS Gem n.1

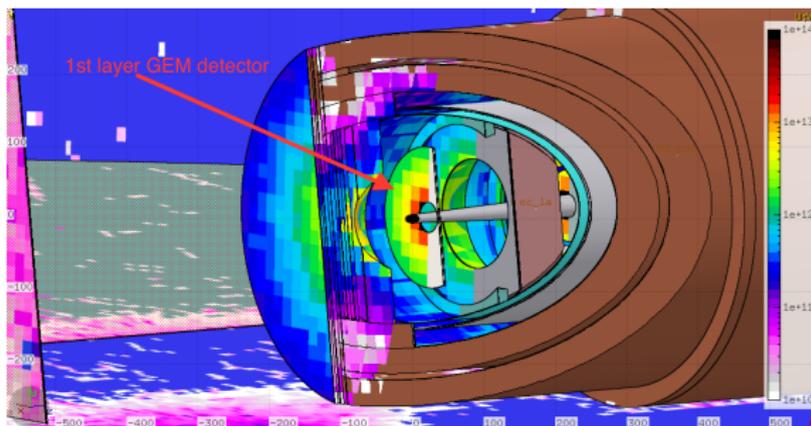


# Radiation GEM detector for ( $J/\Psi$ )

## Accumulated fluence in the Hall

Accumulated  $\left(\frac{1\text{MeV}_{eq}\text{Neutron}}{\text{cm}^2}\right)$  for 60 days,  $3\mu\text{A}$  beam at 11GeV

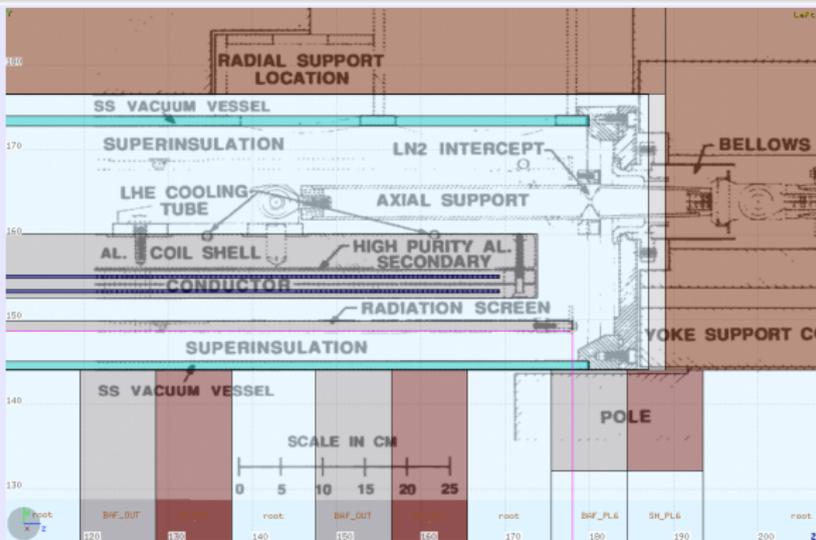
- The GEM readout system was developed to sustain  $2.4 \times 10^{14} \left(\frac{1\text{MeV}\text{Neutron}}{\text{cm}^2}\right)$
- Radiation is well below the threshold for the electronics



# Lifetime on NbTi superconductor carried by SoLID

## Updated Coil design to CLEO

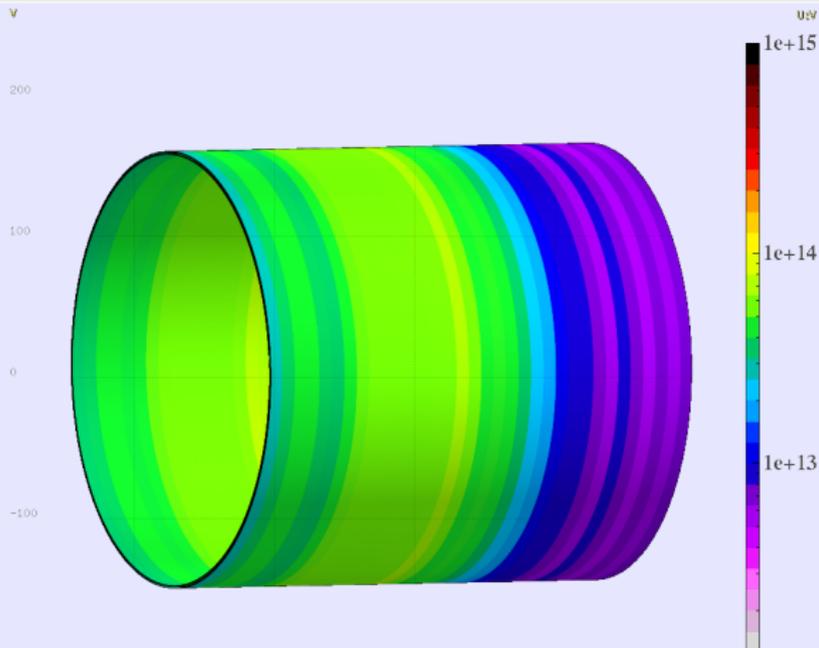
The PVDIS configuration with Deuterium target present the main source for neutron fluxes on the coils



# Lifetime on NbTi superconductor carried by SoLID

Expected PVDIS neutron fluence  $\frac{N}{cm^2} (E > 1MeV)$

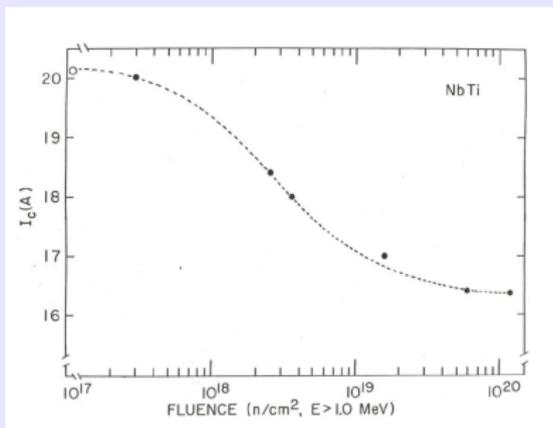
Dose for 2000h at  $100\mu A$  (Flux on coils)



# Lifetime on NbTi superconductor carried by SoLID

Expected PVDIS neutron fluence  $\frac{N}{\text{cm}^2} (E > 1\text{MeV})$

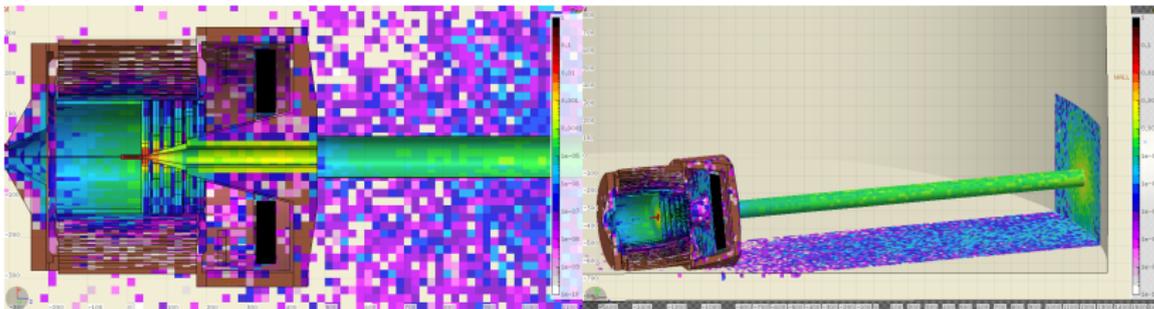
Dose



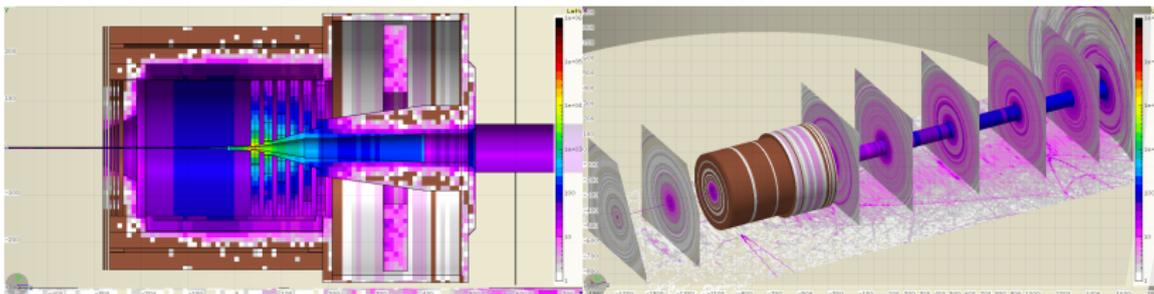
- A reduction of  $\sim 20\%$  in  $I_c$  is expected in the range  $2 \times 10^{17} < \frac{N}{\text{cm}^2} < 2 \times 10^{19}$
- **The expected accumulated fluence for PVDIS is  $< 10^{14} \frac{N}{\text{cm}^2}$**

# SoLID PVDIS: Power and Activation

$E_{dep}(W)/cm^3$  PVDIS, Liquid D target (100 $\mu$ A)

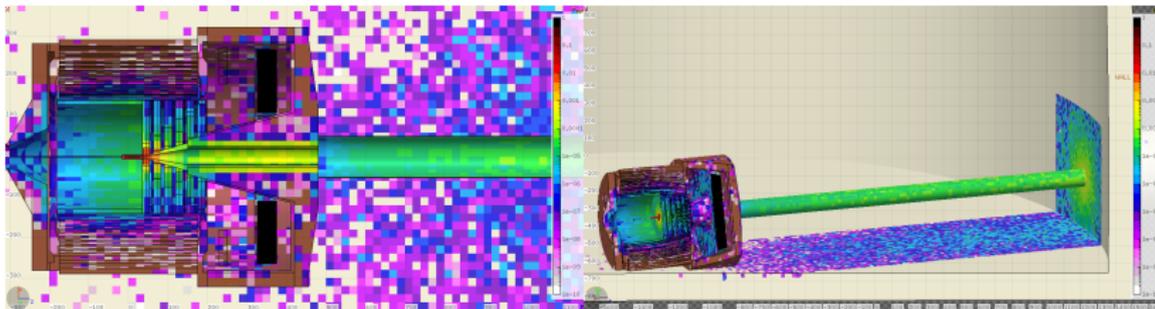


$Dose_{eq}(mrem)/h$  after 1 hour from beam exposure (1 Month running time)

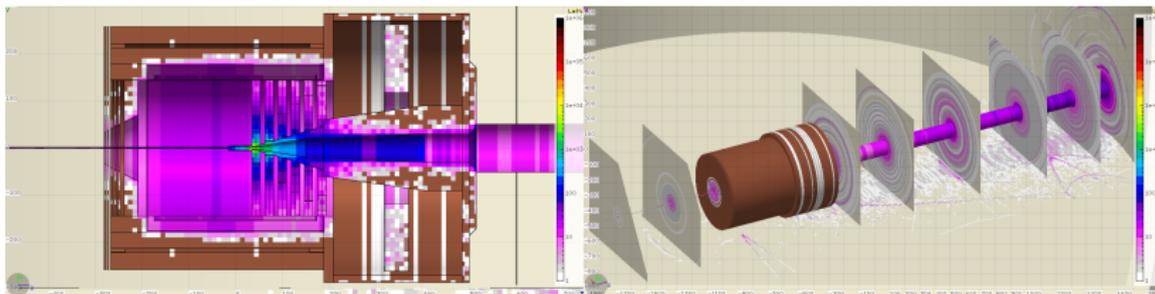


# SoLID PVDIS: Power and Activation

$E_{dep}(W)/cm^3$  PVDIS, Liquid D target ( $100\mu A$ )

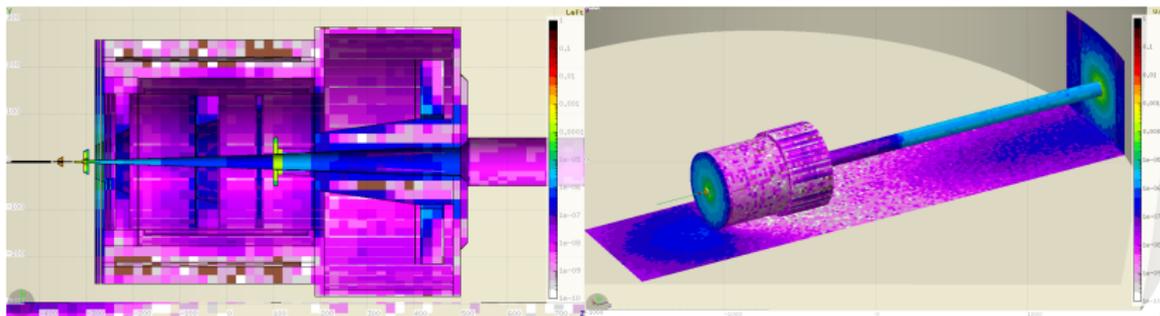


$Dose_{eq}(mrem)/h$  after 1day from beam exposure (1 Month running time)

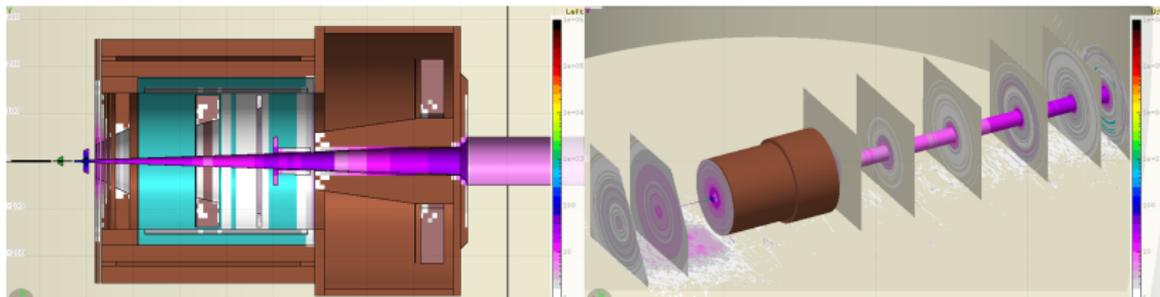


# SoLID SIDIS: Power and Activation

$E_{dep}(W)/cm^3$  SIDIS, Liquid  $^3He$  target ( $15\mu A$ )

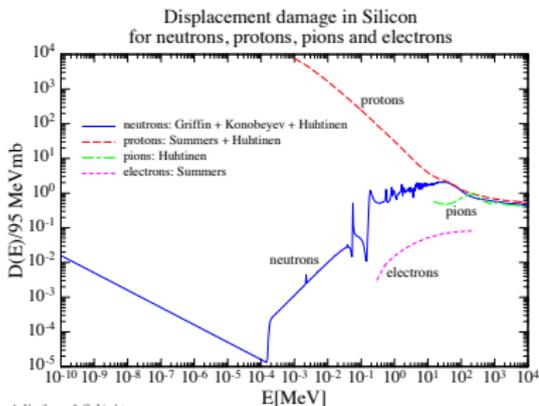


$Dose_{eq}(mrem)/h$  after 1 hour from beam exposure (1 Month running time)

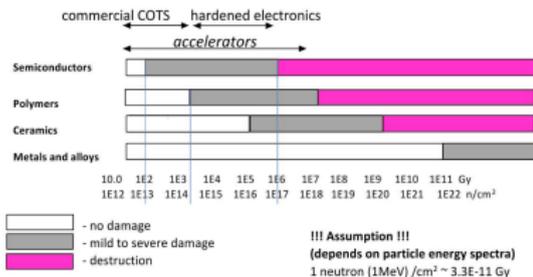


# Radiation Estimates and Tolerance

## Radiation Estimates



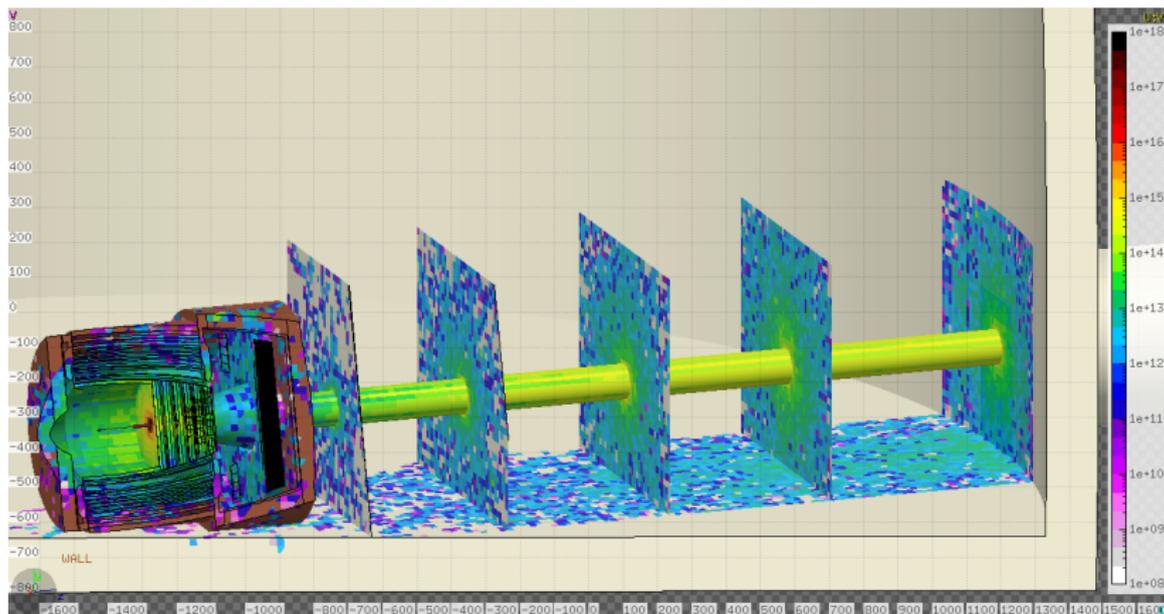
## Tolerance (guideline)



© Lockheed Martin

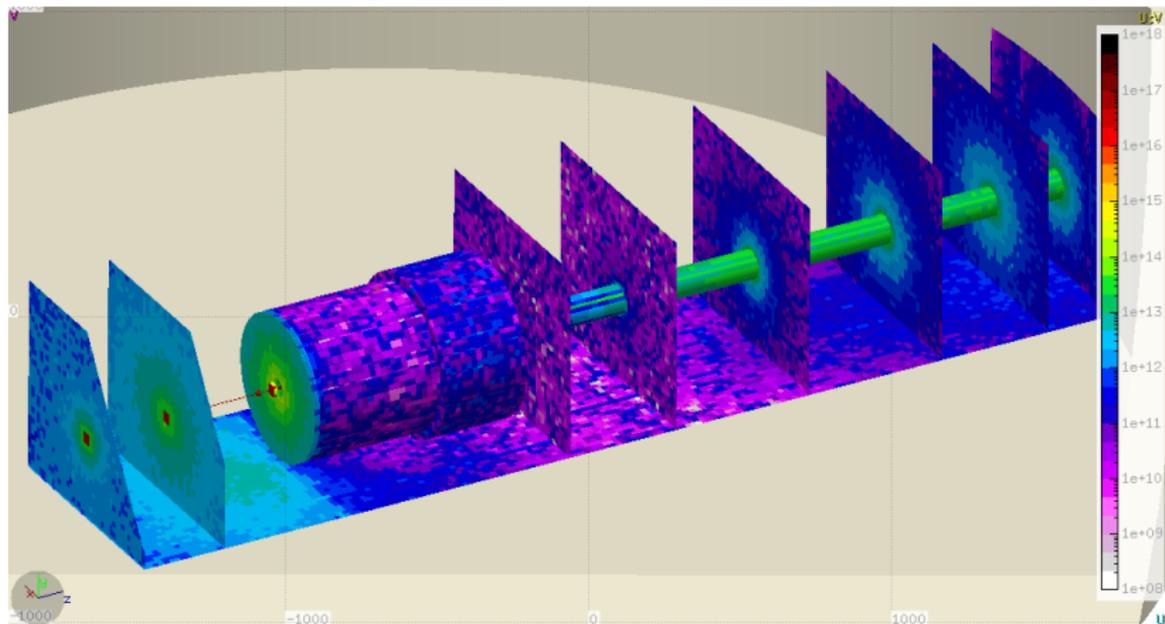
# SoLID PVDIS: 1MeVeq Neutrons

*Neutrons(1MeV – eq)/cm<sup>2</sup> PVDIS, Liquid D target  
 (100μA for 2000hours)*



# SoLID SIDIS: 1MeVeq Neutrons

*Neutrons(1MeV – eq)/cm<sup>2</sup> SIDIS, Liquid <sup>3</sup>He target  
 (15μA for 3000hours)*

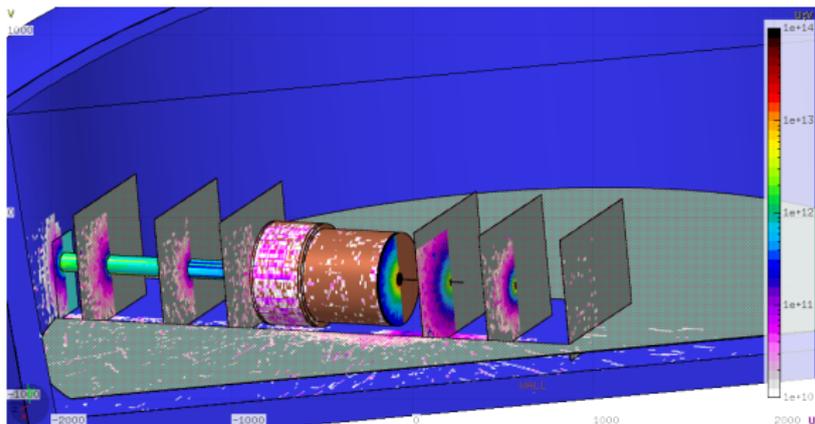


# Radiation in the Hall ( $J/\psi$ )

## Accumulated fluence in the Hall

Accumulated  $\left(\frac{1\text{MeV}_{eq}\text{Neutron}}{\text{cm}^2}\right)$  for 60 days,  $3\mu\text{A}$  beam at 11GeV

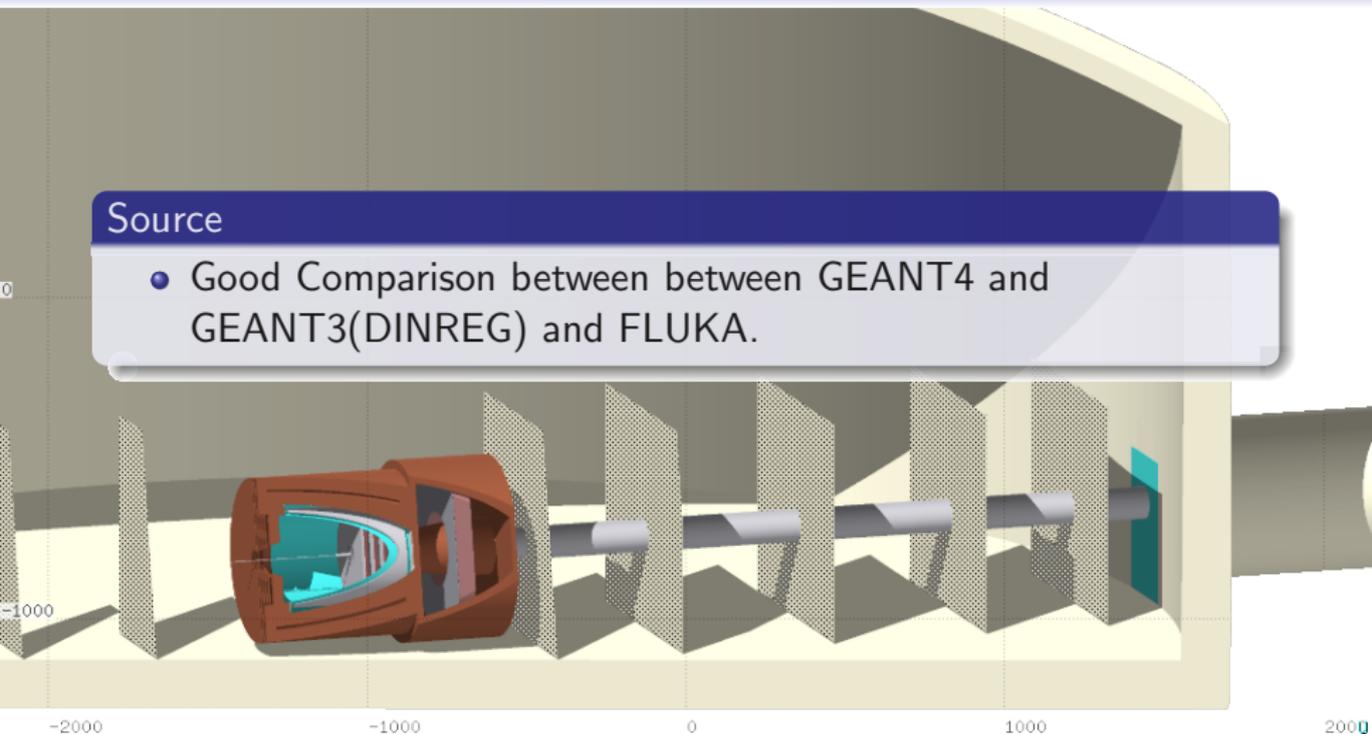
- $10^{13}$   $\left(\frac{1\text{MeV}\text{Neutron}}{\text{cm}^2}\right)$  as goal for safety
- Radiation in the Hall seems well under control



# Conclusions

## Source

- Good Comparison between between GEANT4 and GEANT3(DINREG) and FLUKA.







# Conclusions

## Activation

- PVDIS:
  - ① Peak of power deposited downstream of the beamline.
  - ② Dose due to activation peaks  $\sim 100\text{mrem/h}$  after 1h
- SIDIS:
  - ① Peak of power deposited downstream of the beamline and on face of magnet.
  - ② Dose due to activation peaks  $\sim 10\text{mrem/h}$  after 1h
- $(J/\Psi)$ :
  - ① Peak of power deposited downstream of the beamline and on face of magnet.
  - ② Dose due to activation peaks  $\sim 10\text{mrem/h}$  after 1h

## Radiation in the Hall

- PVDIS: Problems if electronics installed in area surrounding downstream beamline  $\sim 10^{15} \frac{N_{1\text{MeVeq}}}{\text{cm}^2}$